

VRRM	IF (TC≤135℃)	QC
1200V	17.5A	43nC

Applications:

- Switch Mode Power Supplies
- Power Factor Correction
- Motor drive, PV Inverter, Wind Power Station

Features:

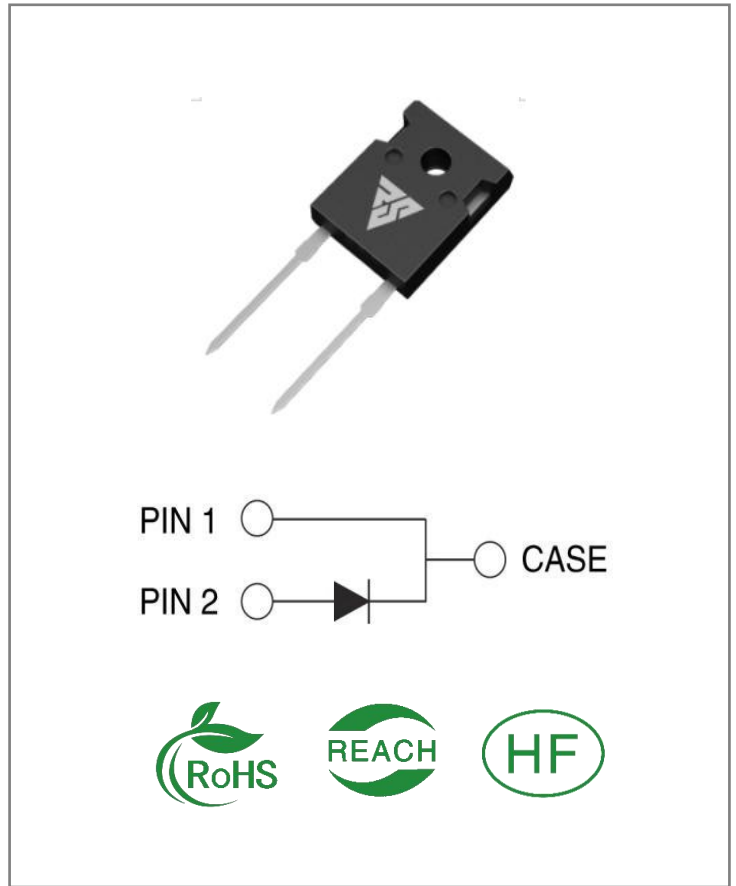
- Zero Reverse Recovery Current
- Zero Forward Recovery Voltage
- Positive Temperature Coefficient on VF
- Temperature-independent Switching
- 175°C Operating Junction Temperature

Benefits:

- Replace Bipolar with Unipolar Device
- Reduction of Heat Sink Size
- Parallel Devices Without Thermal Runaway
- Essentially No Switching Losses

Ordering Information

Part Number	Package	Marking	Packing	Qty.
RSS15120W	TO-247-2	RSS15120W	Tube	30 PCS



Maximum Ratings (T_J= 25°C unless otherwise specified)

Symbol	Parameter	Value	Unit	Test Conditions	Note
VRRM	Repetitive Peak Reverse Voltage	1200	V	TC = 25°C	
VRSM	Surge Peak Reverse Voltage	1200	V	TC = 25°C	
VR	DC Blocking Voltage	1200	V	TC = 25°C	
IF	Forward Current	37	A	TC ≤ 25°C	
		17.5		TC ≤ 135°C	
		15		TC ≤ 144°C	
IFRM	Repetitive Peak Forward Surge Current	135	A	TC = 25°C, tp =8.3ms, Half Sine Wave	
Ptot	Power Dissipation	183	W	TC = 25°C	Fig.3
TC	Maximum Case Temperature	144	°C		
TJ,TST G	Operating Junction and Storage Temperature	-55 to175	°C		

Electrical Characteristics (T_J= 25°C unless otherwise specified)

Symbol	Parameter	Typ.	Max.	Unit	Test Conditions	Note
VF	Forward Voltage	1.55	1.8	V	IF = 15A, T _J = 25°C	Fig.1
		2.2	2.5		IF = 15A, T _J = 175°C	
IR	Reverse Current	5	20	μA	VR = 1200V, T _J = 25°C	Fig.2
		20	200		VR = 1200V, T _J = 175°C	
C	Total Capacitance	940	/	pF	VR = 1V, T _J = 25°C, f = 1MHz	Fig.5
		70			VR = 400V, T _J = 25°C, f = 1MHz	
		57			VR = 800V, T _J = 25°C, f = 1MHz	
QC	Total Capacitive Charge	43	/	nC	VR =800V,	Fig.4

Thermal Characteristics (T_J= 25°C unless otherwise specified)

Symbol	Parameter	Typ.	Unit	Note
RθJC	Thermal Resistance from Junction to Case	0.82	°C/W	Fig.6

Typical Feature Curve

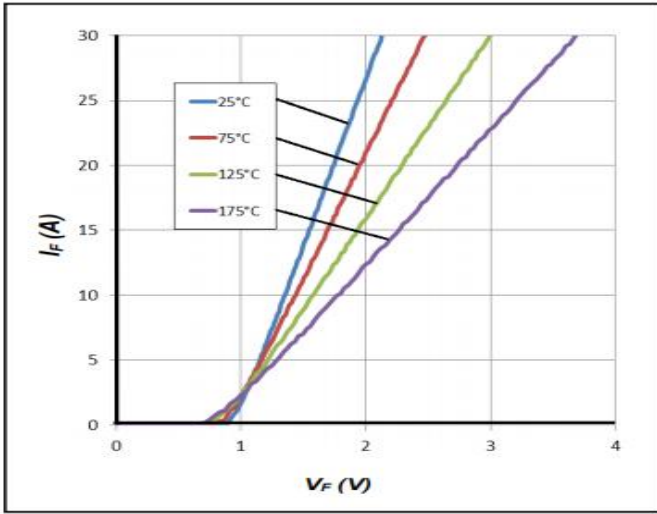


Figure 1. Forward Characteristics

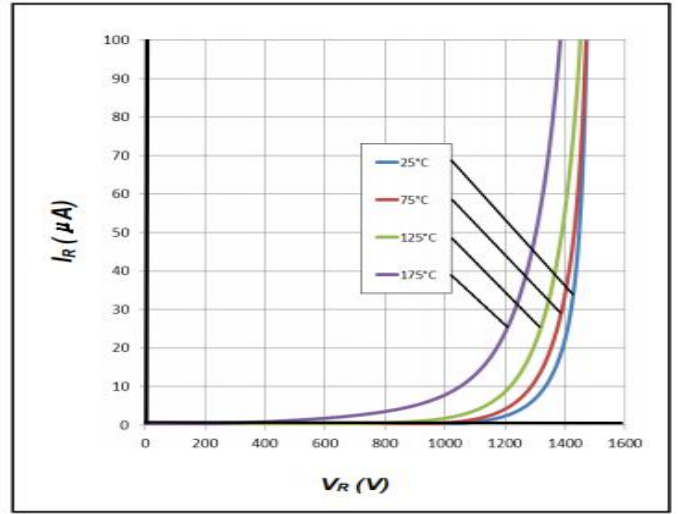


Figure 2. Reverse Characteristics

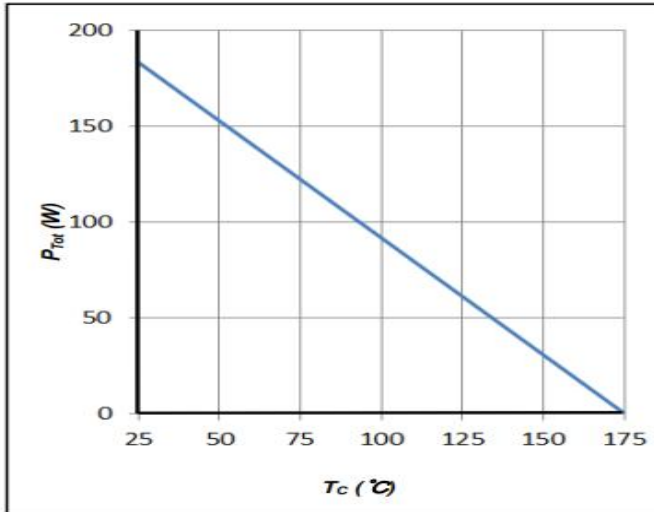


Figure 3. Power Derating

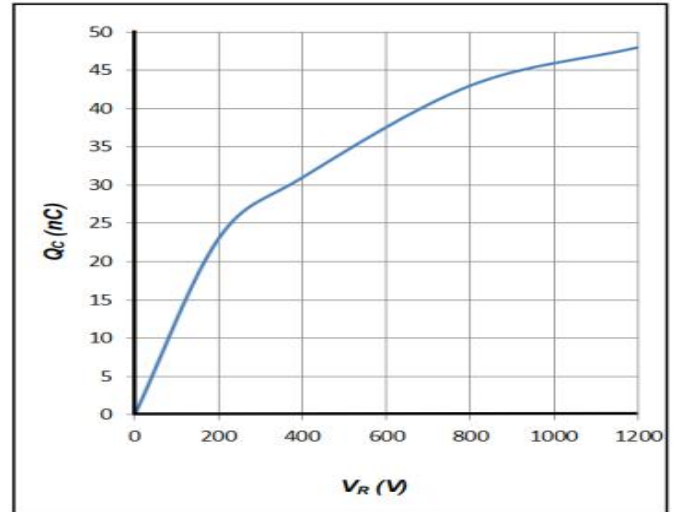


Figure 4. Total Capacitive Charge vs. Reverse Voltage

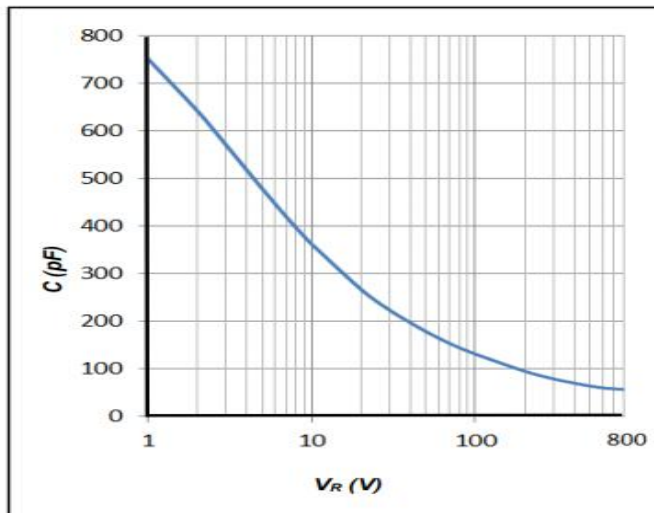


Figure 5. Total Capacitance vs. Reverse Voltage

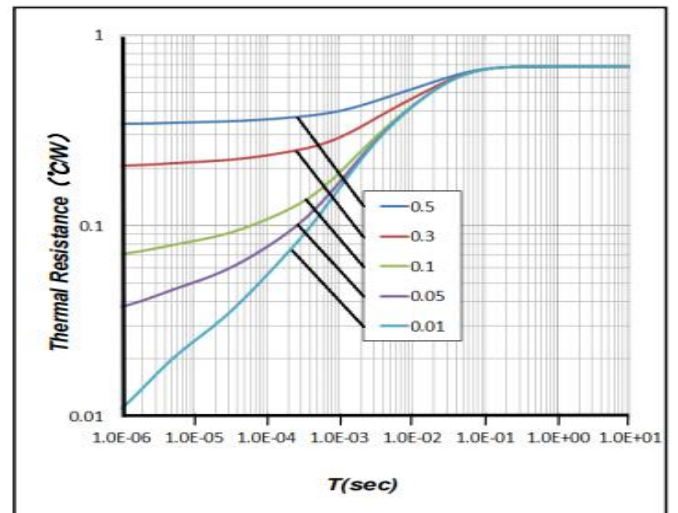
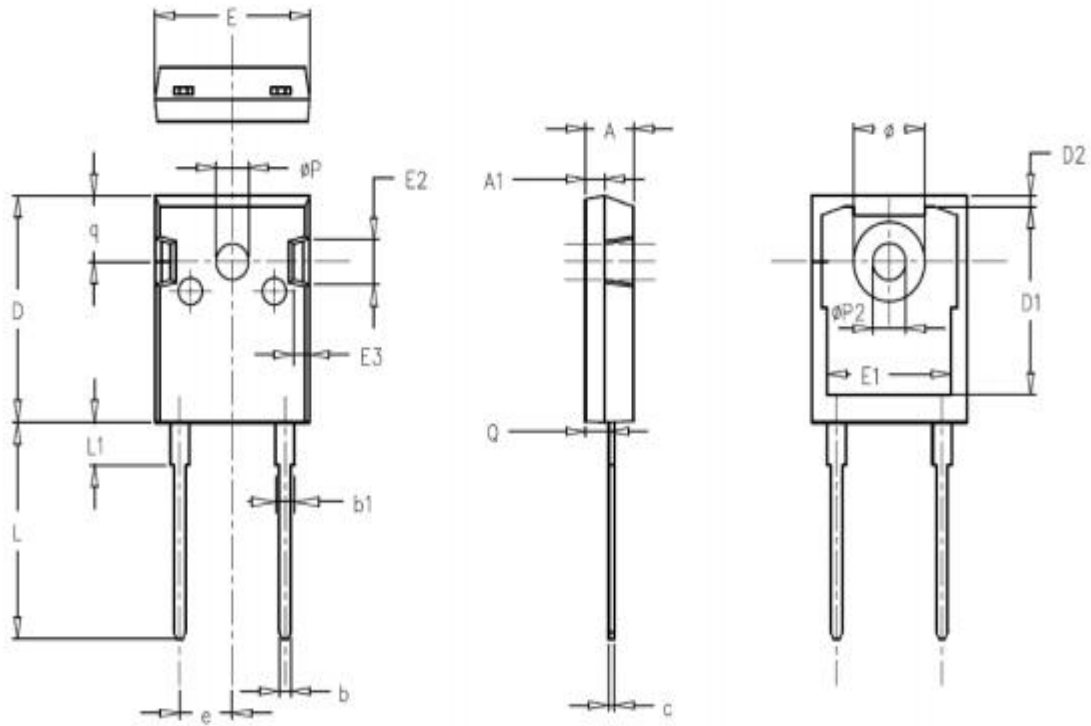


Figure 6. Transient Thermal Impedance

Package outline drawing(TO-247-2 Unit: mm)



SYMBOL	MILLIMETERS			NOTES	SYMBOL	MILLIMETERS			NOTES
	Normal	MIN.	MAX.			Normal	MIN.	MAX.	
A	4.98	4.68	5.36		ϕP	3.66	3.45	3.85	
A1	1.99	1.90	2.10		e	5.44	BSC		
Q	2.41	2.30	2.60		q	6.24	5.99	6.58	
c	0.60	0.48	0.72		$\phi P2$	3.45	3.24	3.64	
b	1.20	1.00	1.40		ϕ	7.14	7.10	7.30	
b1	2.07	1.90	2.30		D1	16.56	16.10	17.10	
D	21.10	20.80	21.80		D2	0.98	0.80	1.36	
E	15.98	15.38	16.20		E1	13.30	13.00	13.52	
L	20.28	19.50	20.50		E2	5.64	5.10	6.10	
L1	4.01	3.75	4.35		E3	2.33	1.90	2.70	

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